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Effect of oxygen on power frequency breakdown voltage and decomposition characteristics of the $C_5F_{10}O/N_2/O_2$ gas mixture

Yue Zhang,^a Xiaoxing Zhang,^{*ba} Yi Li,^{*a} Yalong Li,^a Qi Chen,^a Guozhi Zhang,^b Song Xiao^a and Ju Tang^a

Sulfur hexafluoride (SF_6) is widely used in the power industry because of its excellent insulation and arc extinguishing performance; however, as the global environment is deteriorating, the need to replace SF_6 is becoming significantly critical. In recent years, $C_5F_{10}O$ has received extensive attention as a potential alternative to SF_6 . In this study, a part of N_2 in $C_5F_{10}O/N_2$ was replaced by O_2 , and the breakdown voltages of $C_5F_{10}O/N_2/O_2$ at different oxygen concentrations under a slightly uneven electric field were tested. The dispersion of breakdown voltage and the discharge decomposition components of $C_5F_{10}O/N_2/O_2$ with different oxygen concentrations were analysed. It was found that as the oxygen concentration increased, the breakdown voltage of $C_5F_{10}O/N_2/O_2$ with 15 kPa $C_5F_{10}O$ at 0.2 MPa increased, and the dispersion of the breakdown voltage became worse. When 0.5% O_2 or more O_2 was added to the $C_5F_{10}O/N_2$ gas mixture, the carbon precipitates on the electrode surface disappeared. As the oxygen concentration continued to increase, another characteristic component, CF_2O , could be detected, whereas C_2F_4 and C_3F_6 disappeared. It is believed that O_2 can inhibit the formation of C_2F_6 , C_3F_8 , C_4F_{10} , and C_3F_7H . Therefore, it is recommended to use oxygen as the second buffer gas for the engineering applications of $C_5F_{10}O$. Moreover, the ratio of $C_5F_{10}O$ to O_2 is recommended to be 1 : 1.

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1 Introduction

The gas insulated switchgear (GIS) has become an indispensable part of the power system due to its advantages such as small size and high operational reliability.^{1–5} Sulfur hexafluoride (SF_6) is widely used in the GIS as a gas insulating medium with high dielectric strength and excellent arc extinguishing performance.^{6–8} However, the global warming potential (GWP) value of SF_6 is as high as 23 500, and its atmospheric lifetime is about 3200 years, SF_6 is one of the most greenhouse gases.^{9–11} Therefore, the demand to limit the application of SF_6 in the power industry is urgent.^{12–14} In this regard, researchers have paid significant attention to find alternative gases for SF_6 from the perspective of insulation strength, environmental characteristics, decomposition properties as well as safety. Over the past three years, fluorocarbon macromolecules, such as $c-C_4F_8$, CF_3I , C_4F_7N , $C_5F_{10}O$, and $C_6F_{12}O$, have attracted attention.^{15–25} Among these molecules, $C_5F_{10}O$ has shown significant advantages in terms of insulation strength, low GWP and reliable biosafety. The molecular structure of $C_5F_{10}O$ is shown in

Fig. 1; $C_5F_{10}O$ is a non-toxic, colourless, and odourless substance.

Its chemical properties are stable; according to the data provided by 3MTM, the initial decomposition temperature of $C_5F_{10}O$ is up to 600 °C, whereas the temperature of the hottest spot in the equipment is usually less than 200 °C.²⁶ In addition, $C_5F_{10}O$ has the GWP of only 1, and its atmospheric lifetime is only 14 days. Moreover, the ozone depletion potential (ODP)

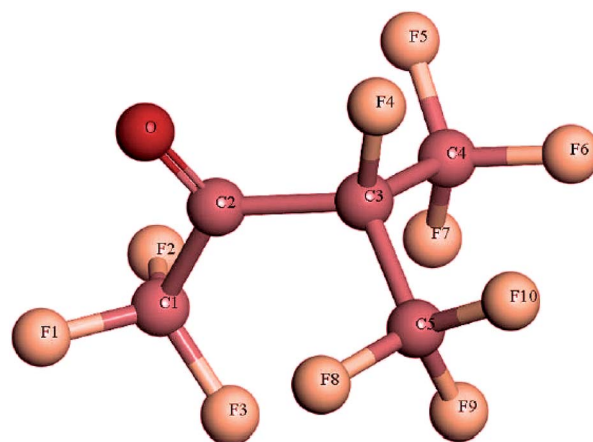


Fig. 1 Molecular structure of $C_5F_{10}O$.

^aSchool of Electrical Engineering and Automation, Wuhan University, Wuhan 430072, China. E-mail: xiaoxing.zhang@outlook.com; liyi_wuhuee@163.com

^bSchool of Electrical and Electronic Engineering, Hubei University of Technology, Wuhan 430072, China

value of $C_5F_{10}O$ is zero; this means that $C_5F_{10}O$ does not consume the ozone layer of the atmosphere and fully meets the requirements of the "Montreal Protocol on Substances that Deplete the Ozone Layer".²⁶ The insulation strength of pure $C_5F_{10}O$ is twice that of SF_6 ; however, the liquefaction temperature of pure $C_5F_{10}O$ under normal pressure is high (*i.e.* 26.9 °C); therefore, it is usually mixed with a buffer gas that has very low liquefaction temperature during its research and practical application.^{27,28}

Recently, several studies have been carried on $C_5F_{10}O$ gas mixtures. Saxegaard *et al.* have demonstrated that the use of $C_5F_{10}O$ /air with the liquefaction temperature of −25 °C can increase the rated voltage of an air switchgear from 12 kV to 24 kV.²⁹ In addition, it has been reported that the AirPlus™ ring network unit of ABB in the Netherlands meets the insulation expectations well and has no impact on the equipment life in the first year.³⁰ Wang *et al.* tested the power-frequency (AC) breakdown characteristics of $C_5F_{10}O/CO_2$ under a non-uniform electric field. They believe that the insulation performance of the gas mixture can be effectively improved by increasing the content of $C_5F_{10}O$.³¹ Aints *et al.* found that an increase in the content of $C_5F_{10}O$ in $C_5F_{10}O$ /air would reduce the effective ionization coefficient.³² Chachereau *et al.* have found that there is a significant synergy between $C_5F_{12}O$ and N_2 or CO_2 , and the $C_5F_{12}O$ gas mixtures can reach the insulation strength requirement of SF_6 by increasing the gas pressure.³³

In addition, it is important to study the decomposition characteristics of the $C_5F_{10}O$ gas mixtures. Our team calculated the decomposition mechanism of $C_5F_{10}O$ using density functional theory (DFT). It has been found that the activity of carbonyl in the $C_5F_{10}O$ molecule (as shown in Fig. 1) is strong. And, C1–C2 and C2–C3 in the $C_5F_{10}O$ molecule easily break to form $CF_3CO\cdot$ and $C_3F_7\cdot$ or $C_3F_7CO\cdot$ and $CF_3\cdot$.^{34,35} Wang *et al.* have also explored the decomposition pathway of $C_5F_{10}O$ and pointed out that the C2–C3 and C3–C4 (or C3–C5) bonds in the $C_5F_{10}O$ molecule are more likely to break.¹⁸ The main decomposition components for the AirPlus™ switchgear after arc extinguishing are CO_2 , CO , and HF , among others, and it has been considered that the toxicity of the $C_5F_{10}O$ gas mixture is mainly determined by CO .³⁶ Hammer *et al.* detected the decomposition components of $C_5F_{10}O/N_2$ under a dielectric barrier discharge. Several by-products such as CO , C_2F_6 , and C_3F_8 were detected.³⁷

Previous studies have shown that the addition of O_2 to a $C_5F_{10}O/CO_2$ gas mixture can improve the insulation strength of the $C_5F_{10}O$ gas mixture.³⁸ However, at present, only few studies have been reported on the influence of O_2 on the insulation and decomposition properties of a $C_5F_{10}O$ gas mixture. In this study, $C_5F_{10}O$ was mixed with N_2 , and O_2 was added as the second buffer gas. By adjusting the oxygen concentration, the breakdown voltage and decomposition components of a $C_5F_{10}O/N_2/O_2$ ternary gas mixture after AC breakdown tests were investigated. The influence of oxygen on the insulation and decomposition properties of the $C_5F_{10}O/N_2/O_2$ gas mixture was explored first. Relevant results can provide reference for the engineering application of a $C_5F_{10}O$ gas mixture.

2 Test equipment, conditions and methods

2.1 Test equipment and conditions

Fig. 2 shows the gas insulation performance and composition analysis platform. The output voltage of the high-voltage test transformer (100 kV/0.5 A) was adjusted by an induction voltage regulator. The AC voltage applied on the electrodes was measured by a voltage divider capacitor. Moreover, protective resistance (10 kΩ) was used to limit the short-circuit current during gap breakdown to prevent damage to the test transformer. Gas chromatography and mass spectrometry (GC/MS) were used for the qualitative analysis of the decomposition components.

A slightly uneven electric field is the most common electric field in the SF_6 equipment. In the experiments to explore the insulation and decomposition characteristics of a potential SF_6 substitute gas, sphere–sphere electrodes with the gap distance of 2 mm were used to simulate the slightly uneven electric field (the non-uniform coefficient of the electric field was calculated to be 1.02 by COMSOL Multiphysics with $E_{\max} = 2.04 \times 10^7$ V m^{-1} and $E_{av} = 2 \times 10^7$ V m^{-1}). The sphere–sphere electrodes are made of brass, and their radius is 25 mm.

Although the insulation strength of the $C_5F_{10}O$ gas mixtures can be increased by increasing the content of $C_5F_{10}O$ in the gas mixture, high liquefaction temperature of $C_5F_{10}O$ under normal pressure will severely limit the application of $C_5F_{10}O$ in high-voltage gas insulation equipment.²⁹ Exploration of the application of $C_5F_{10}O$ gas mixtures in medium-voltage or low-voltage gas insulated equipment (GIE) has become the focus of research in the industry. For this reason, all the experiments in this study were carried out under the condition of the absolute pressure of 0.2 MPa.

Considering the low liquefaction temperature of nitrogen and oxygen (−140.7 °C and −118.57 °C, respectively), the liquefaction temperature of a $C_5F_{10}O$ gas mixture under normal pressure is determined by the partial pressure of $C_5F_{10}O$ in the gas mixture.³⁹ In this study, the partial pressure of $C_5F_{10}O$ was set to 15 kPa, and the corresponding liquefaction temperature

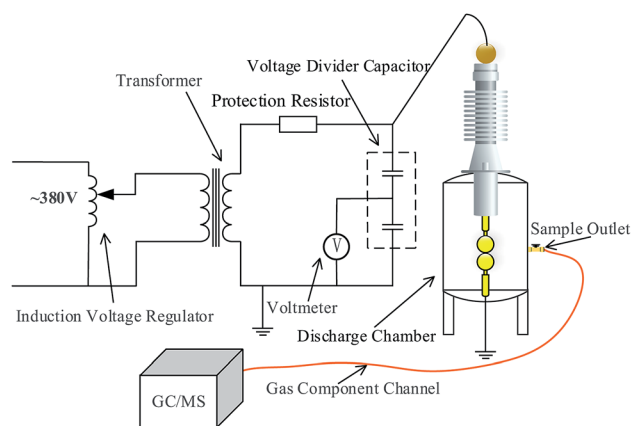


Fig. 2 Gas insulation performance test and gas composition analysis platform.



of the gas mixtures was $-15\text{ }^{\circ}\text{C}$. In addition, because the pressure remains unchanged, the addition of oxygen will reduce the nitrogen concentration accordingly.

To investigate the effect of oxygen concentration on the breakdown voltage and decomposition characteristics of $\text{C}_5\text{F}_{10}\text{O}/\text{N}_2/\text{O}_2$, herein, four groups of gas mixtures with the oxygen concentrations of 0%, 0.5%, 7.5% and 19.33% were tested. The corresponding partial pressure of oxygen was 1 kPa when the oxygen concentration was 0.5%. The oxygen concentration of 7.5% corresponded to the oxygen partial pressure of 15 kPa (*i.e.* $\text{C}_5\text{F}_{10}\text{O} : \text{O}_2$ was equal to 1 : 1), and when the oxygen concentration was 19.33%, the partial pressure of oxygen was 38.66 kPa (actually, it was a gas mixture of $\text{C}_5\text{F}_{10}\text{O}$ and air).

2.2 Test methods

The gas chamber was vacuum-pumped and then filled with buffer gas until the absolute pressure was greater than 0.2 MPa. Then, the abovementioned steps were repeated three times to ensure that each test was unaffected by previous tests and other impurities in the chamber. Because of the low saturated vapor pressure of $\text{C}_5\text{F}_{10}\text{O}$ at normal temperature, it should be filled into the chamber first followed by oxygen and nitrogen. It was necessary to stand the gas mixture for 24 hours to make it mix evenly. The power frequency voltage was applied to the discharge chamber by a step-up method with a gap of at least 5 minutes between every two breakdowns. A total of 60 breakdown tests were conducted for each group of gas mixture. The average value of the breakdown voltage of the first ten breakdowns was taken as the breakdown voltage of $\text{C}_5\text{F}_{10}\text{O}/\text{N}_2/\text{O}_2$ under each oxygen concentration condition.

The $\text{C}_5\text{F}_{10}\text{O}/\text{N}_2/\text{O}_2$ samples after 60 times breakdown were obtained and tested by GC/MS. Moreover, the qualitative analysis of the gas was carried out by comparing the scanned results of the standard gas chromatography with the standard chromatographic database of the National Institute of Standards and Technology (Nist14.0).

3 Test results and analysis

3.1 Effect of oxygen concentration on the breakdown voltage of $\text{C}_5\text{F}_{10}\text{O}/\text{N}_2/\text{O}_2$

As shown in Fig. 3, the breakdown voltage of $\text{C}_5\text{F}_{10}\text{O}/\text{N}_2/\text{O}_2$ increases with the increasing oxygen concentration. The electronegativity of oxygen is greater than that of nitrogen, and its ability to attract electrons is stronger; thus, oxygen is more likely to hinder the development of discharge. Therefore, in the case of constant pressure and $\text{C}_5\text{F}_{10}\text{O}$ concentration, the dielectric strength of the $\text{C}_5\text{F}_{10}\text{O}$ gas mixture will increase with the increasing oxygen content.

Fig. 4 shows the breakdown voltage values of $\text{C}_5\text{F}_{10}\text{O}/\text{N}_2/\text{O}_2$ for 60 breakdown tests under different oxygen concentration conditions. Due to the random nature of discharge, the standard deviation is defined to characterize the dispersion of the breakdown voltage of $\text{C}_5\text{F}_{10}\text{O}/\text{N}_2/\text{O}_2$ at different oxygen concentrations. The formula for the calculation is as follows:

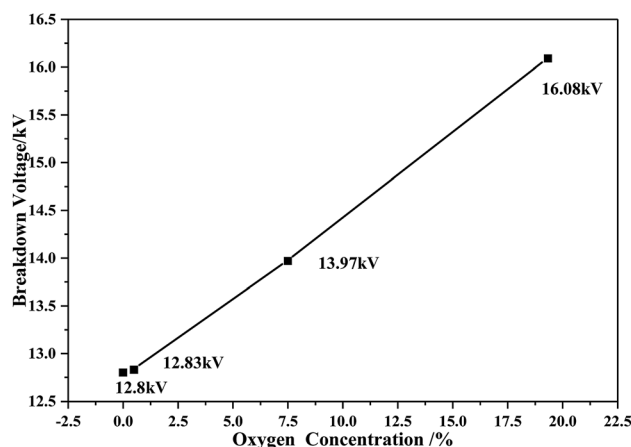


Fig. 3 Relationship between the oxygen concentration and breakdown voltage of $\text{C}_5\text{F}_{10}\text{O}/\text{N}_2/\text{O}_2$.

$$\sigma = \sqrt{\frac{1}{N-1} \sum_{i=1}^N (x_i - \bar{x})^2} \quad (1)$$

where N is the number of samples ($N = 60$), x_i is the breakdown voltage value of the i th time, \bar{x} is the average value, and σ is the standard deviation of the breakdown voltage of the experimental set.

When the oxygen concentration was 0%, the breakdown voltages of $\text{C}_5\text{F}_{10}\text{O}/\text{N}_2/\text{O}_2$ for 60 times breakdown were around 12.8 kV with $\sigma = 0.40$. For gas mixture with 0.5% oxygen, a few data points deviated from 12.83 kV, and $\sigma = 0.46$; with an increase in the oxygen concentration to 7.5%, the amount of the breakdown voltage data deviating from 13.97 kV increased, and $\sigma = 0.83$. When the oxygen concentration gradually increased to 19.33%, most of the breakdown voltage values deviated from 16.08 kV, and $\sigma = 1.08$.

Overall, the breakdown voltage of $\text{C}_5\text{F}_{10}\text{O}/\text{N}_2/\text{O}_2$ increased as the oxygen concentration increased; however, most of the breakdown voltage data deviated from the average breakdown voltage values, and σ became larger; this indicated that the dispersion of gas insulation strength gradually became worse.

3.2 Effect of oxygen concentration on the decomposition characteristics of $\text{C}_5\text{F}_{10}\text{O}/\text{N}_2/\text{O}_2$

Fig. 5 and 6 show the detection results of the $\text{C}_5\text{F}_{10}\text{O}/\text{N}_2/\text{O}_2$ components before and after breakdown obtained by GC/MS in the SCAN mode. As shown in Fig. 5, there are no other impurities in the gas.

Fig. 6 shows the component detection results of the $\text{C}_5\text{F}_{10}\text{O}$ gas mixture with different oxygen concentrations after 60 times breakdown. Since no substance is detected before 4.4 min and after 7 min, to facilitate the description of the discharge decomposition components of the $\text{C}_5\text{F}_{10}\text{O}$ gas mixture, only the GC/MS scan results from 4.25 to 6.25 min are shown in Fig. 6. Considering that the breakdown voltage is positively related to the energy generated during breakdown, we have plotted the scanning results of the discharge decomposition components of



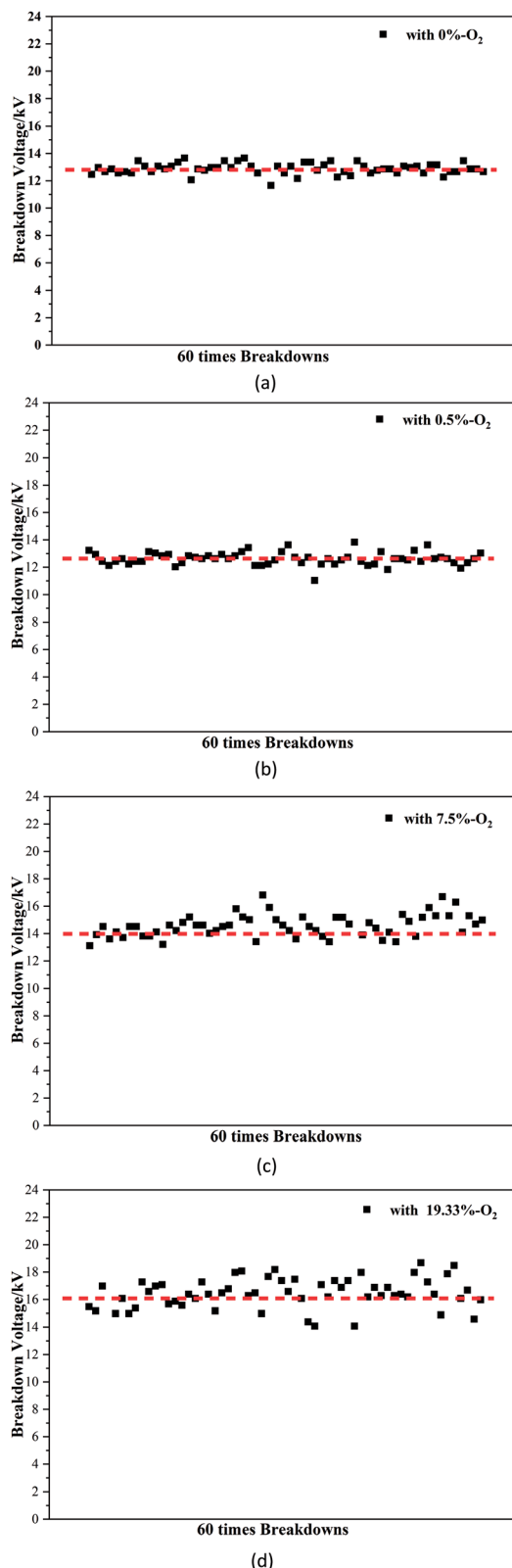


Fig. 4 60 times breakdown voltage of $C_5F_{10}O/N_2/O_2$ under different oxygen concentrations.

the $C_5F_{10}O$ gas mixture at different oxygen concentrations in the same figure in turn. Therefore, the yield of each component can be compared intuitively by the peak area of each component.

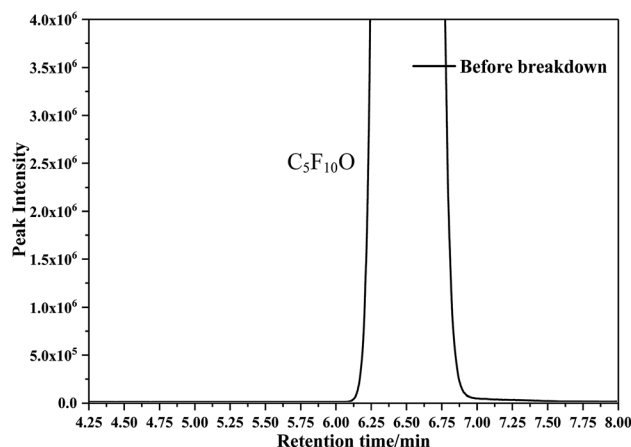


Fig. 5 Components before breakdown.

As shown in Fig. 6a, when the oxygen concentration was 0%, the characteristic peaks of CF_4 , C_2F_6 , C_3F_8 , C_2F_4 , C_4F_{10} , C_3F_6 and C_3F_7H were found. Moreover, the peak area of C_2F_6 is largest. The peak area of CF_4 is significantly less than that of C_2F_6 . However, when 0.5% oxygen was added to the gas mixture, the content of C_3F_7H was reduced relative to the case when the oxygen concentration was 0%. The content of other components is close to that of the $C_5F_{10}O$ gas mixture without oxygen.

As shown in Fig. 6b, when the oxygen concentration is increased from 0.5% to 7.5%, the content of C_2F_6 is greatly reduced, and the peak area of CF_4 is close to that of C_2F_6 . Moreover, the contents of C_3F_8 and C_4F_{10} are greatly reduced. In addition, C_2F_4 and C_3F_6 are not detected in the gas mixture with 7.5% oxygen, and a small amount of CF_2O is detected at 4.757 min. The content of CO_2 increased when compared with that of the gas mixture with 0.5% oxygen. The contents of most of the decomposition components of the $C_5F_{10}O$ gas mixture with 7.5% oxygen are lower than those of the gas mixture with 0.5% oxygen, except for CF_2O and CO_2 . Thus, the addition of oxygen inhibits the formation of macromolecules such as C_2F_6 , C_3F_8 , C_4F_{10} , and C_3F_7H .

As shown in Fig. 6c, when the oxygen content increases from 7.5% to 19.33%, the peak area of CF_4 is closer to that of C_2F_6 . The peak areas of CF_4 , C_2F_6 , CF_2O , C_3F_8 , CO_2 , C_4F_{10} and C_3F_7H increased to different extents. Among them, the peak area of CF_2O is significantly increased. Note that oxygen cannot be considered to promote the production of C_2F_6 , C_3F_8 , C_4F_{10} , etc. As the oxygen concentration increases, the breakdown voltage increases as well; thus, the greater energy generated during the discharge breakdown causes more $C_5F_{10}O$ to decompose; this results in an increase in the decomposition of the $C_5F_{10}O$ gas mixture.

To more clearly illustrate the inhibitory effect of oxygen on the formation of C_2F_6 , C_3F_8 , C_4F_{10} and C_3F_7H , the results of the decomposition components of the $C_5F_{10}O$ gas mixtures with the oxygen concentrations of 0% and 19.33% were compared, as shown in Fig. 7.

As shown in Fig. 6c, when the oxygen concentration increased from 7.5% to 19.33%, the breakdown voltage



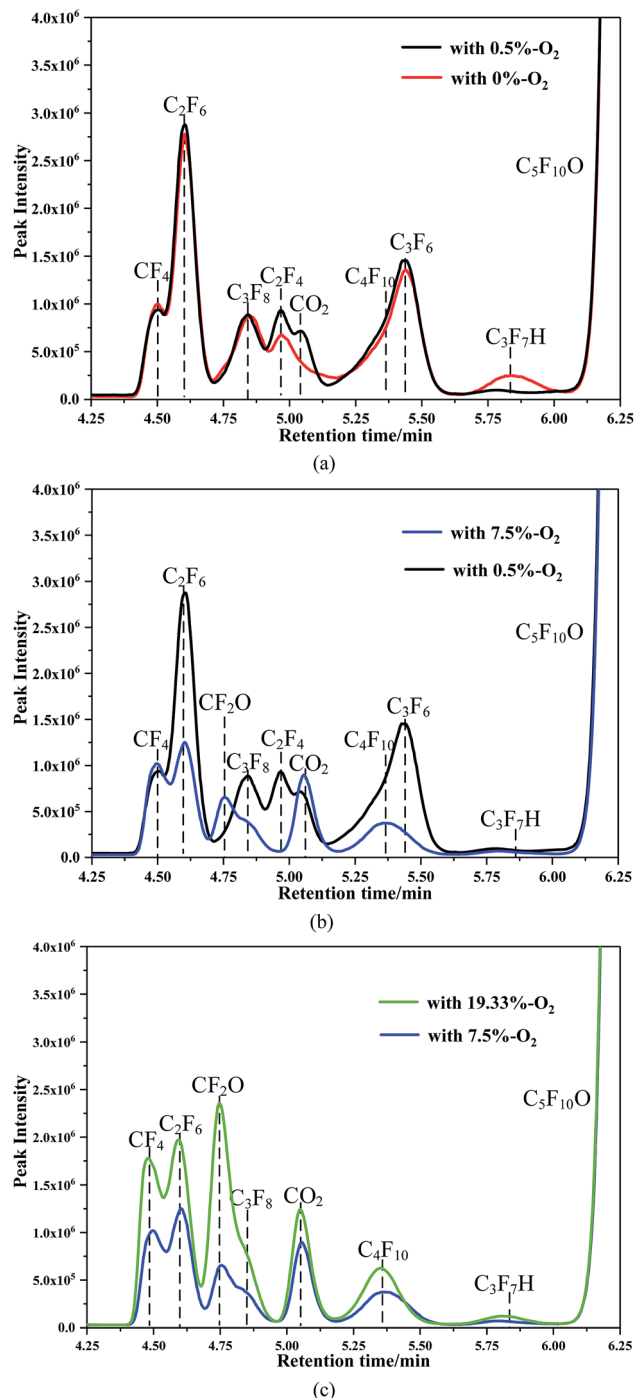


Fig. 6 Components after 60 times breakdown with different oxygen concentrations.

increased by 2.11 kV; this resulted in a significant increase in the contents of the decomposition components of the $C_5F_{10}O$ gas mixture. However, as shown in Fig. 7, the breakdown voltage of $C_5F_{10}O/N_2$ increased from 12.8 kV to 16.08 kV (an increase by 3.28 kV) when the oxygen concentration was increased from 0% to 19.33%. However, the contents of C_2F_6 , C_3F_8 , C_4F_{10} and C_5F_{12} for the $C_5F_{10}O$ gas mixture with 19.33% oxygen were not more than those of the $C_5F_{10}O$ gas mixture without oxygen addition.

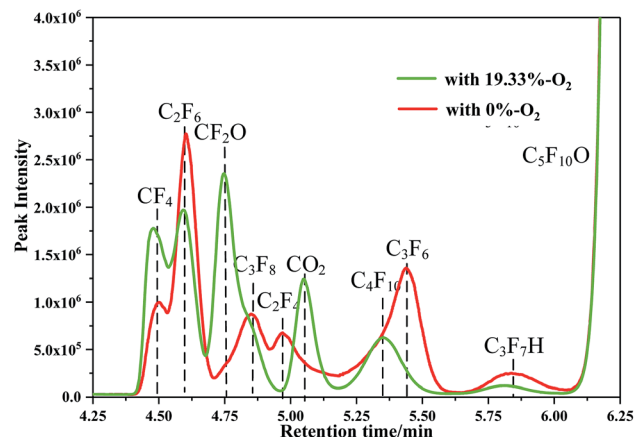


Fig. 7 Components after 60 times breakdown with different oxygen concentrations.

The electrode surfaces with and without oxygen were also compared. As shown in Fig. 8, it was found that a small amount of black substance was adhered to the surface for the gas mixture without oxygen addition after 60 times of breakdown (Fig. 8 left). When the oxygen concentration was 0.5% or more, only discharge ablation traces could be observed (Fig. 8 right). Therefore, it can be believed that oxygen can inhibit the precipitation of carbon black when $C_5F_{10}O$ decomposes. This may be because the generated carbon particles in the discharge can react with oxygen to produce carbon dioxide in the presence of a high-energy electric field.

Moreover, when the oxygen concentration was 0.5%, C_2F_6 and C_3F_6 still existed, and CF_2O was not detected. When the oxygen concentration was increased to 7.5% or more, C_2F_4 and C_3F_6 were not detected in the decomposition components, whereas CF_2O began to appear, and its content increased with an increase in oxygen concentration.

Under certain conditions, O_2 will react with C_2F_4 and C_3F_6 . Several studies have reported the reaction between O atoms and C_2F_4 or C_3F_6 . In the literature,⁴⁰ a mercury lamp was used to irradiate N_2O to produce O atoms, which could react with C_2F_4 or C_3F_6 and produce CF_2O . Moreover, in literature,⁴¹ it has been mentioned that the carbon-carbon double bond ($C=C$) of C_2F_4 and C_3F_6 weakens after ionization. Another study⁴² has pointed

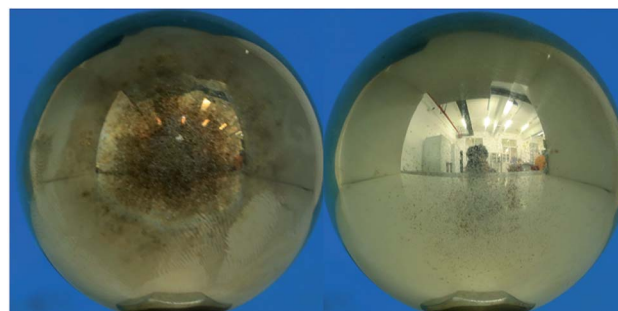
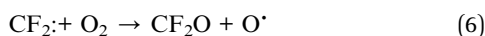
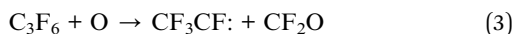


Fig. 8 (Left) Electrode surface after 60 times breakdown of $C_5F_{10}O/N_2$ (right) electrode surface after 60 times breakdown of $C_5F_{10}O/N_2/O_2$.



out that the O atoms can attack C=C in C₃F₆ leading to the generation of CF₂O and CF₃CF₂. Moreover, CF₃CF₂ will rapidly undergo spin relaxation and then form C₂F₄. Due to the difference in the experimental conditions, these studies can only provide reference for the mechanism of CF₂O production in our experiments. Based on these studies as well as our team's computational study on the mechanism of CF₂O production when studying the decomposition characteristics of CF₃I,⁴³ the following pathways can be obtained.



4 Discussion

The uniformity of the electric field is vulnerable to the conductive particles in the insulating gap and causes local aggrandizement of the electric field.²⁶ Although under our experimental conditions, the carbon black adhered on the electrodes had less effect on the dispersion of the breakdown voltage, with an increase in the operating voltage and time, the amount of carbon black increased, and when it accumulated to a certain extent, the insulation safety of the equipment was seriously threatened.

Note that CF₂O is highly toxic, and its LC50 (Lethal Concentration 50, 4 h) value is only 270 mg m⁻³ (inhaled by rats). According to the Globally Harmonized System of Classification and Labelling of Chemicals toxicity classification standard, the acute inhalation toxicity of CF₂O is level 1. It has a strong stimulating effect on respiratory mucosa and can cause chemical pneumonia, pulmonary edema, and acute poisoning. Inevitably, the equipment contains a small amount of water, and CF₂O itself is highly corrosive and easily reacts with water to release highly toxic corrosive gases such as HF, thereby affecting the operating life of the equipment. However, note that although CF₂O is highly toxic, CF₂O is irritating as well, and the occurrence of gas leakage is easily detected in time. In addition, CF₂O is soluble in water and ethanol; thus, the waste gas can be treated harmlessly. Therefore, the toxicity of the decomposition products of a C₅F₁₀O mixture will not affect its application in the power industry to a large extent.

Although the breakdown voltage of C₅F₁₀O/N₂/O₂ increases with an increase in oxygen concentration and there is no inflection point value in the curve of breakdown voltage and oxygen concentration, this does not mean that it is reasonable to increase the oxygen concentration or even replace all N₂ to increase the insulation strength of C₅F₁₀O/N₂/O₂. In fact, when the oxygen concentration is 7.5% (C₅F₁₀O : O₂ is 1 : 1), the breakdown voltage of C₅F₁₀O/N₂/O₂ reaches 53.20% that of SF₆

under the same conditions (the power frequency breakdown voltage of SF₆ tested herein is 26.26 kV). It is possible to achieve the insulation requirements of the SF₆ equipment by increasing the pressure of the C₅F₁₀O gas mixture.⁴⁴ In addition, a partial discharge will inevitably occur during the long-term operation of the equipment, which will lead to the decomposition of the insulation medium. If C₅F₁₀O/N₂/O₂ with higher insulation strength is pursued by further increasing the oxygen concentration, the service life of the equipment and the safety of the field personnel will be greatly threatened. For this reason, it is recommended to use oxygen as the second buffer gas for C₅F₁₀O; however, it is not recommended to increase the dielectric strength of C₅F₁₀O/N₂/O₂ by greatly increasing the oxygen concentration. In the practical application of C₅F₁₀O/N₂/O₂, the 1 : 1 ratio of C₅F₁₀O : O₂ can be considered.

5 Conclusion

In this study, the breakdown voltages of C₅F₁₀O/N₂/O₂ at different oxygen concentrations were tested by a gas insulation performance test and gas composition analysis platform. The dispersion of the C₅F₁₀O/N₂/O₂ discharge breakdown voltage was analyzed, and the decomposition components were compared. The following conclusions can be obtained:

(1) When the absolute pressure is 0.2 MPa and the partial pressure of C₅F₁₀O is 15 kPa, the breakdown voltage of C₅F₁₀O/N₂/O₂ and its dispersion increase with an increase in oxygen concentration under a slightly uneven electric field.

(2) The carbon precipitates on the electrode surfaces disappear after multiple discharge breakdowns when 0.5% or more O₂ is added to the gas mixture.

(3) With an increase in the oxygen concentration, the peak area of CF₄ in the C₅F₁₀O/N₂/O₂ gas mixture gradually approaches that of C₂F₆. When the oxygen content reaches 7.5%, C₂F₄ and C₃F₆ disappear due to reaction with oxygen to form CF₂O. The addition of oxygen inhibits the formation of C₂F₆, C₃F₈, C₄F₁₀ and C₃F₇H to a certain extent.

(4) CF₂O generated after the C₅F₁₀O/N₂/O₂ discharge breakdown is highly corrosive and extremely toxic, which is harmful to the equipment and personnel. Therefore, it is not preferable to increase the dielectric strength of C₅F₁₀O/N₂/O₂ by further increasing the oxygen concentration. The recommended C₅F₁₀O : O₂ ratio is 1 : 1.

Conflicts of interest

There are no conflicts to declare.

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